SUPSIC®

Parameter	Symbol	Rating	Units	
Load Voltage	VL	200	V	
Load Current	I∟	0.2	Α	
On-Resistance	Ron	5	Ω	
I/O Isolation Voltage	V/ıo	5000	Vrms	





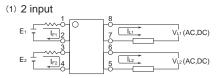
SMD-8

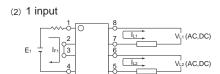
DIP-8



1,3. LED Anode

2,4. LED Cathode 5,6. Drain (MOS FET) 7,8. Drain (MOS FET)





SUPSiC PhotoRelays

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

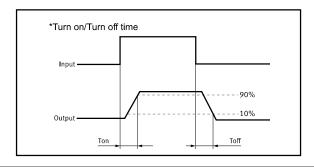
Applications

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems

- Robotics
- Aerospace
- Home/Safety security systems
- **Process Control**
- **Energy Management**
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Output Rating		Poolsogo	Part No.	Packing Quantity		
Category	Load Voltage Load Current		Package	Fait No.	Packing Quantity	
AC/DC 200V 200mA	DIP-8	GAQW217E	50pcs /tube			
	200mA	SMD-8	GAQW217EH	1000pcs /reel		





Absolute Maximum Ratings (Ta = 25°C)

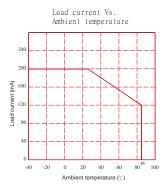
	Item	Symbol	Value	Units	Note
	Continuous LED Current	lF	50	mA	
Input	Peak LED Current	I FP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pin	75	mW	
	Load Voltage	V∟	200	V(AC peak or DC)	
	Load Current	l.	0.2	А	
Output	Peak Load Current	Peak	0.5	А	100ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Power	Dissipation	Р⊤	500	mW	
I/O Isolation	n Voltage	V _{I/O}	5000	Vrms	RH=60%, 1min
Operating Te	emperature	Торг	-40 to 85	℃	
Storage Tem	nperature	T _{stg}	-40 to 100	℃	
Pin Soldering	g Temperature	T _{sol}	260	℃	10 sec max.

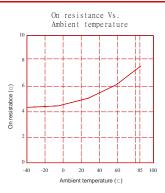
Electrical Characteristics (Ta = 25°C)

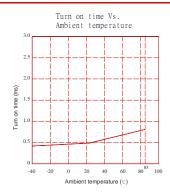
	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
	LED Forward Voltage	VF		1.2	1.4	V	I⊧=10mA
	Operation LED Current	Fon		0.5	2.0	mA	
Input	Recovery LED Current	Foff		0.35	0.5	mA	
	Recovery LED Voltage	V _{Foff}	0.7			٧	
							I⊧=5mA,I∟=100mA,
	On-Resistance	Ron		5	8	Ω	Time to flow is within 1 sec.
Output	Off-State Leakage	Leak	0.01	0.02	0.1	uA	V _∟ =Rating
	Current	ILeak	0.01	0.02	0.1	uA	VE-Italing
	Output Capacitance	Cout		70		pF	V∟=0, f=1MHz
Transmis	Turn-On Time	Ton		0.4	0.8	ms	I⊧=5mA, I∟=100mA,
sion	Turn-Off Time	Toff		0.05	0.2	ms	
Counted	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V
Coupled	I/O Capacitance	Ci/o		0.8	1.5	pF	f=1MHz

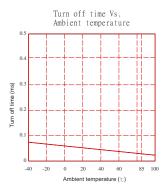
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

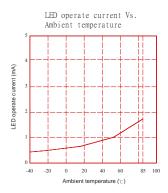
Engineering Data

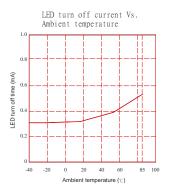


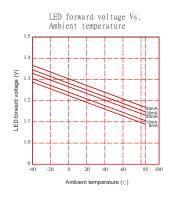


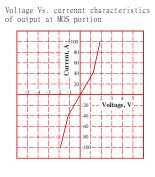


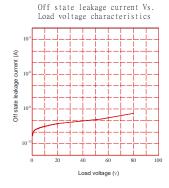


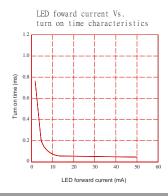


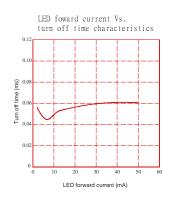


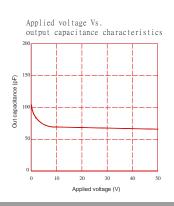










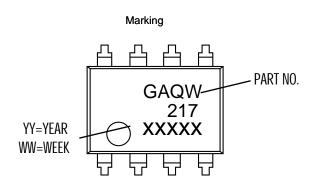


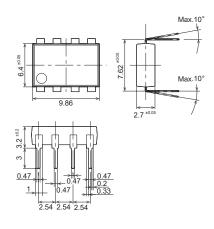


Dimensions and DIP-8 Package

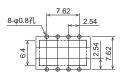
Unit: mm

Through hole terminal type





PC board pattern (Bottom view)



DIP Tape dimensions Unit: mm

Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.

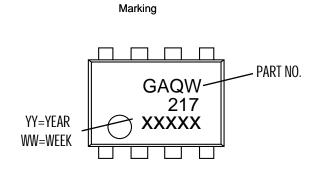


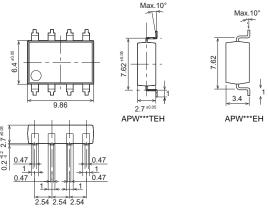
Surface mount terminal type



Dimensions and SMD-8 Package Unit: mm

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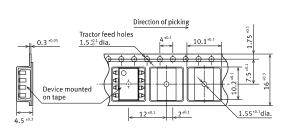


Recommended mounting pad (Top view)

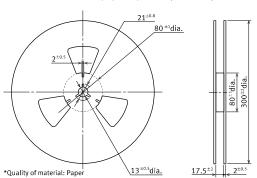


Tape dimensions (tape reel)

Tape dimensions (Unit: mm)



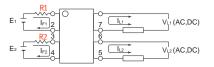
Dimensions of paper tape reel (Unit: mm)





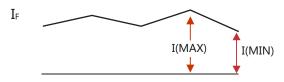
Using Methods

Examples of resistance value to control LED forward current (IF=5mA)



E1 E2	R1 R2(Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA, at I(MIN), and less than 30mA, at I(MAX).



Recommended Operating Conditions

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

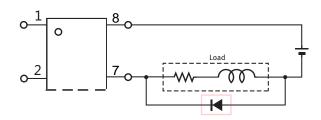
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	lF	5.0	7.0	30	mA

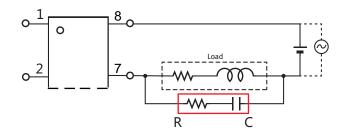
Protection Circuit

Output spike voltages:if an inductive load generates spike voltages which exceed heabsolute maximum rating, the spike voltage shall be limited.

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.





When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.



Recommended Soldering Conditions

(a) Infrared reflow soldering:

■ Peak reflow soldering : 260°C or below (package surface temperature)

■ Time of peak reflow temperature : 10 sec
■ Time of temperature higher than 230°C : 30-60 sec
■ Time to preheat temperature from 180~190°C : 60-120 sec

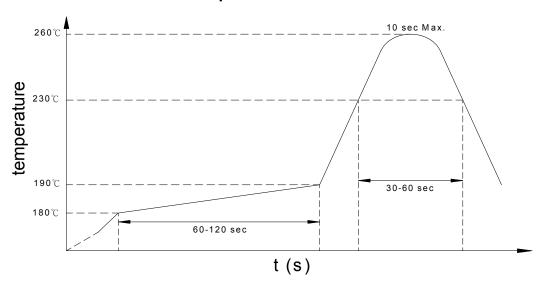
■ Time(s) of reflow: Two

■ Flux : Rosin flux containing small amount of chlorine (The

flux with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



(b) Wave soldering:

■ Temperature : 260°C or below (molten solder temperature)

■ Time : 10 seconds or less

■ Preheating conditions : 120°C or below (package surface temperature)

■ Time(s) of reflow : One

■ Flux: Rosin flux containing small amount of chlorine (The flux with a maximum

chlorine content of 0.2 Wt% is recommended.)

(c) Cautions:

■ Fluxes: Avoid removing the residual flux with freon-based and chlorine-based

cleaning solvent.

Avoid shorting between portion of frame and leads.